Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance.

2. Features and benefits

- · High blocking voltage capability
- High noise immunity
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- · General purpose switching

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | ons Values | | | |
|---------------------|--|--|------------|-----|-----|------|
| Absolute | maximum rating | | | | | |
| V_{DRM} | repetitive peak off-state voltage | | | 600 | | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 91 °C; Fig. 1; Fig. 2; Fig. 3 | 25 | | | А |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; $t_p = 20 \text{ms}$; Fig. 4; Fig. 5 | 190 | | А | |
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static ch | aracteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G+;$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 6 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2+ G-;}$ $T_j = 25 \text{ °C; Fig. 7}$ | - | 10 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G-;}$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 11 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G+;}$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 23 | 70 | mA |

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5. Pinning information

Table 2. Pinning information

| Graphic symbol |
|----------------|
| |
| T2T1 |
| sym051 |
| symus i |
| |
| |
| |

6. Ordering information

Table 3. Ordering information

| Type number | | Package | | | | | | |
|-------------|------------|----------|---|---------|--|--|--|--|
| | | Name | Description | Version | | | | |
| | BTA140-600 | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking codes |
|-------------|---------------|
| BT140-600 | BT140-600 |

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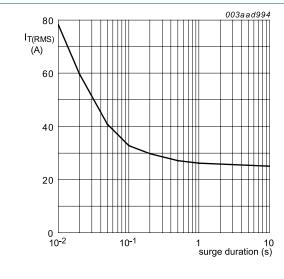
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Values | Unit |
|---------------------|--|--|------------|------------------|
| V_{DRM} | repetitive peak off-state voltage | | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 91°C; Fig 1; Fig 2; Fig 3 | 25 | А |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; $t_p = 20 \text{ms}$; Fig 4; Fig 5 | 190 | А |
| | | full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; $t_p = 16.7 \text{ms}$ | 209 | А |
| l²t | I ² t for fusing | t _p = 10 ms; SIN | 180 | A ² s |
| dl _⊤ /dt | rate of rise of on-state current | I _G = 70 mA; T2+ G+ | 50 | A/µs |
| | | I _G = 70 mA; T2+ G- | 50 | A/µs |
| | | I _G = 70 mA; T2- G- | 50 | A/µs |
| | | I _G = 140 mA; T2- G+ | 10 | A/µs |
| I _{GM} | peak gate current | | 2 | Α |
| P_{GM} | peak gate power | | 5 | W |
| $P_{G(AV)}$ | average gate power | over any 20 ms period | 0.5 | W |
| T _{stg} | storage temperature | | -40 to 150 | °C |
| T _j | junction temperature | | 125 | °C |

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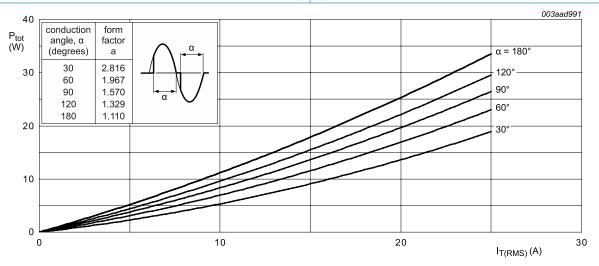


f = 50 Hz; T_{mb} = 91 °C

30 003aad995
I_{T(RMS)}
(A)
20
10
0-50 0 50 100 T_{mb}(°C)

Fig. 2. RMS on-state current as a function of mounting base temperature; maximum values

Fig. 1. RMS on-state current as a function of surge duration; maximum values



 α = conduction angle

 $a = form factor = I_{T(RMS)} / I_{T(AV)}$

Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values

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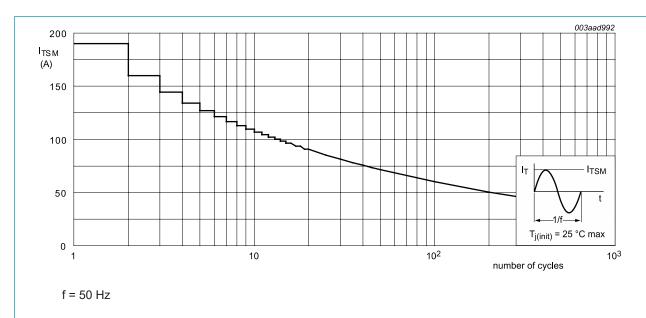
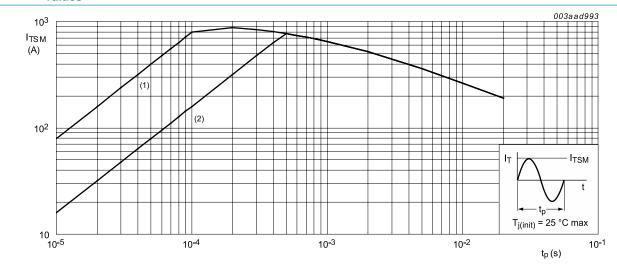


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



t_p ≤ 20 ms

- (1) dl_⊤/dt limit
- (2) T2- G+ quadrant limit

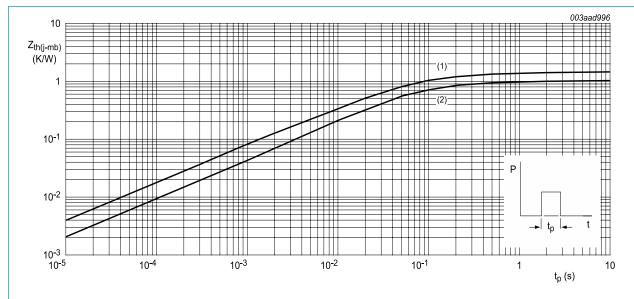
Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|--------------------------|-----|-----|-----|------|
| $R_{\text{th(j-mb)}}$ | thermal resistance | full cycle; Fig 6 | - | - | 1 | K/W |
| | from junction to mounting base | half cycle; <u>Fig 6</u> | - | - | 1.4 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



- (1) Unidirectional (half cycle)
- (2) Bidirectional (full cycle)

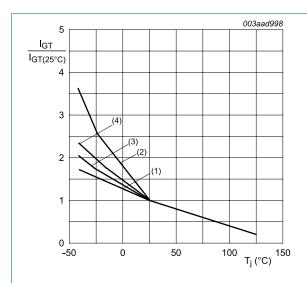
Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse width

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10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|---------------------------------------|--|------|-----|------|------|
| Static ch | aracteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2+ G+;$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 6 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G-;$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 10 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G-;}$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 11 | 35 | mA |
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2- G+;$ $T_j = 25 \text{ °C}; Fig. 7$ | - | 23 | 70 | mA |
| I _L | latching current | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | 8 | 40 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | 30 | 60 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2- G-;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | 18 | 40 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2- G+;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | 15 | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; T2+; <u>Fig. 9</u> | - | 7 | 60 | mA |
| | | V _D = 12 V; T _j = 25 °C; T2-; <u>Fig. 9</u> | | 12 | 60 | mA |
| V _T | on-state voltage | I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.55 | V |
| V_{GT} | gate trigger voltage | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11 | - | 0.7 | 1 | V |
| | | $V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 \text{ °C};$ Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic | characteristics | | | • | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T_{j} = 125 °C; $(V_{DM}$ = 67% of V_{DRM}); exponential waveform; gate open circuit | 100 | 300 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | $V_D = 400 \text{ V}; T_j = 95 \text{ °C}; dI_{com}/dt = 9 \text{ A/}$ ms; $I_T = 25 \text{ A}; gate open circuit}$ | - | 10 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | $I_{TM} = 30 \text{ A}; V_D = 600 \text{ V}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu\text{s}$ | - | 2 | - | μs |



- (1) T2+ G+
- (2) T2+ G-
- (3) T2- G-
- (4) T2- G+

Fig. 7. Normalized gate trigger current as a function of junction temperature

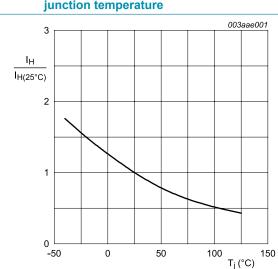


Fig. 9. Normalized holding current as a function of junction temperature

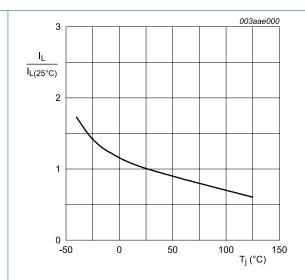
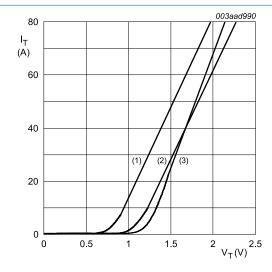


Fig. 8. Normalized latching current as a function of junction temperature



 V_o = 1.073 V; R_s = 0.015 Ω

(1) $T_j = 125$ °C; typical values (2) $T_j = 125$ °C; maximum values (3) $T_j = 25$ °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

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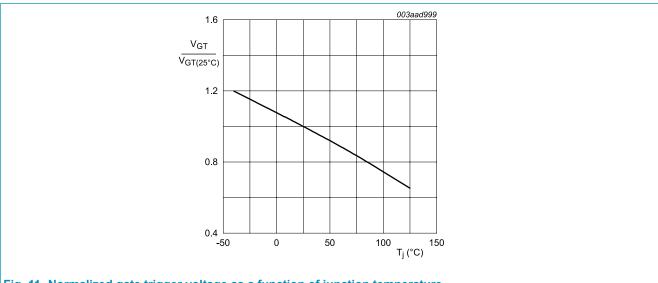
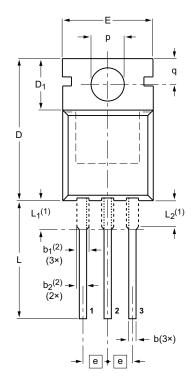


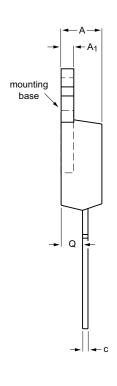
Fig. 11. Normalized gate trigger voltage as a function of junction temperature

11. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78





DIMENSIONS (mm are the original dimensions)

| UNIT | Α | A ₁ | b | b ₁ ⁽²⁾ | b ₂ ⁽²⁾ | С | D | D ₁ | E | е | L | L ₁ ⁽¹⁾ | L ₂ ⁽¹⁾ max. | р | q | Q |
|------|------------|----------------|------------|-------------------------------|-------------------------------|------------|--------------|----------------|-------------|------|--------------|-------------------------------|------------------------------------|------------|------------|------------|
| mm | 4.7 4.1 | 1.40 1.25 | 0.9 0.6 | 1.6 1.0 | 1.3 1.0 | 0.7 0.4 | 16.0 15.2 | 6.6 5.9 | 10.3 9.7 | 2.54 | 15.0 12.8 | 3.30 2.79 | 3.0 | 3.8 3.5 | 3.0 2.7 | 2.6 2.2 |

Notes

- 1. Lead shoulder designs may vary.
- 2. Dimension includes excess dambar.

| | OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | |
|--|---------|-----|-----------------|----------|------------|------------|---------------------------------|
| | VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| | SOT78 | | 3-lead TO-220AB | SC-46 | | | 08-04-23 08-06-13 |

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| Document status [1][2] | Product status [3] | Definition | | |
|---------------------------------------|--------------------|---|--|--|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. | | |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. | | |
| Product Production [short] data sheet | | This document contains the product specification. | | |

- Please consult the most recently issued document before initiating or completing a design.
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For sales office addresses, please send an email to: salesaddresses@ween-semi.com
Date of release: 22 March 2018

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